

Supplementary Information for
**Work function-regulated two-dimensional porous C₇N₆-based
single-atom catalysts for hydrogen evolution reaction**

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To better evaluate the interaction strength between transition metal (TM) and support, the adsorption energies of different TM atoms anchor on C₇N₆ monolayer (TM@C₇N₆) were calculated, as the following formula:

$$E_{\text{ad}} = E_{\text{total}} - (E_{\text{sub}} + E_{\text{TM}})$$

where E_{total} represents the total energy of the system, E_{sub} denotes the energy of the substrate, and E_{TM} corresponds to the energy of the adsorbed TM atom. This definition implies that a more negative value of E_{ad} indicates a more stable adsorption structure.

To examine the electrochemical stability of TM@C₇N₆, the dissociation potential (U_{diss}) was calculated:

$$U_{\text{diss}} = U_{\text{diss}}^0 - \frac{E_{\text{f}}}{Ne}$$

where U_{diss}^0 and N represent the standard dissolution potential of elements in their bulk structure and the number of electrons involved in the dissolution process, respectively.

Additionally, to evaluate the catalytic activity of HER process, Gibbs free energy of H adsorption (ΔG_{H^*}) was calculated based on computational hydrogen electrode (CHE) model, as shown in the following formula:

$$\Delta G = \Delta E_{\text{DFT}} + \Delta E_{\text{ZPE}} - T\Delta S$$

where ΔE_{DFT} , ΔE_{ZPE} , and ΔS represent the adsorption energy of intermediates, change in zero-point energy, and entropy, respectively.

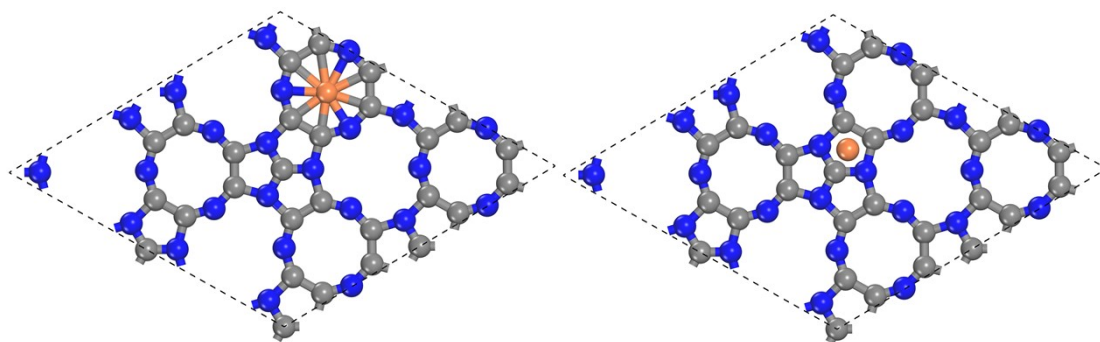


Fig. S1 Geometry structures of TM supported on C_7N_6 in (a) C_6N_3 centers and (b) pentagonal core. The grey, blue, and orange spheres represent C, N and TM elements, respectively.

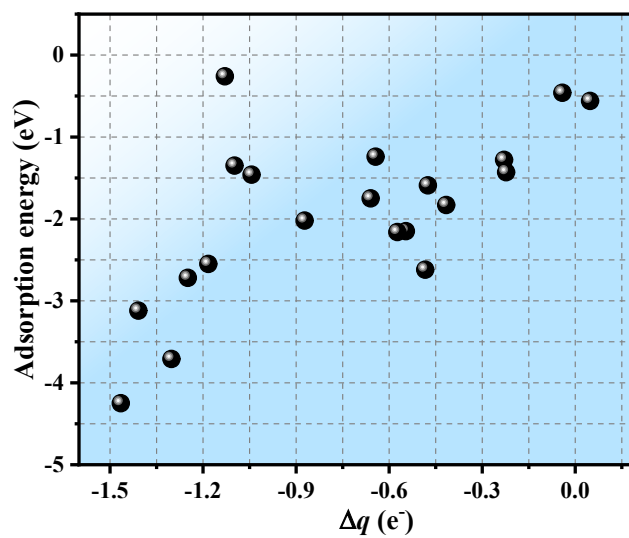
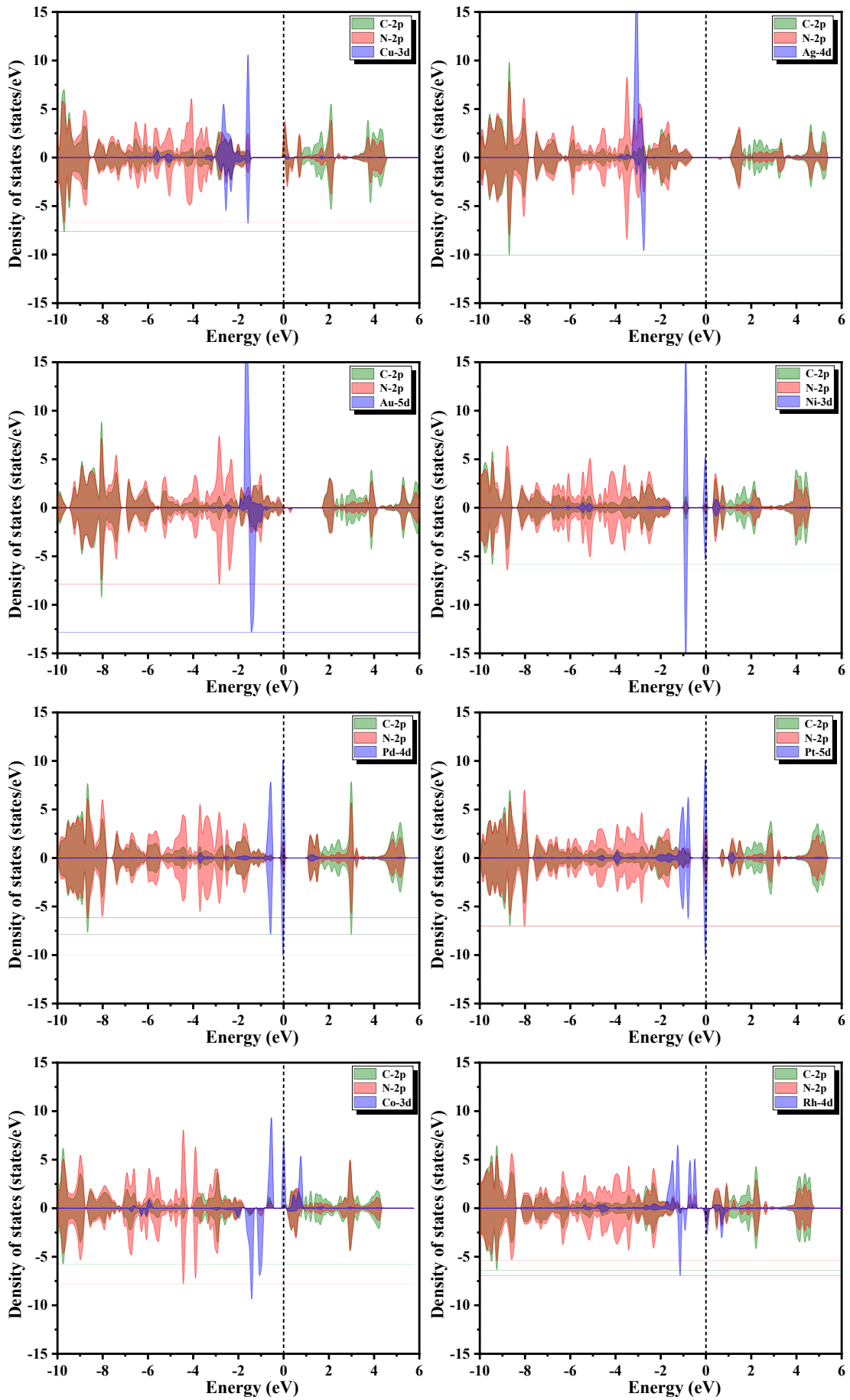
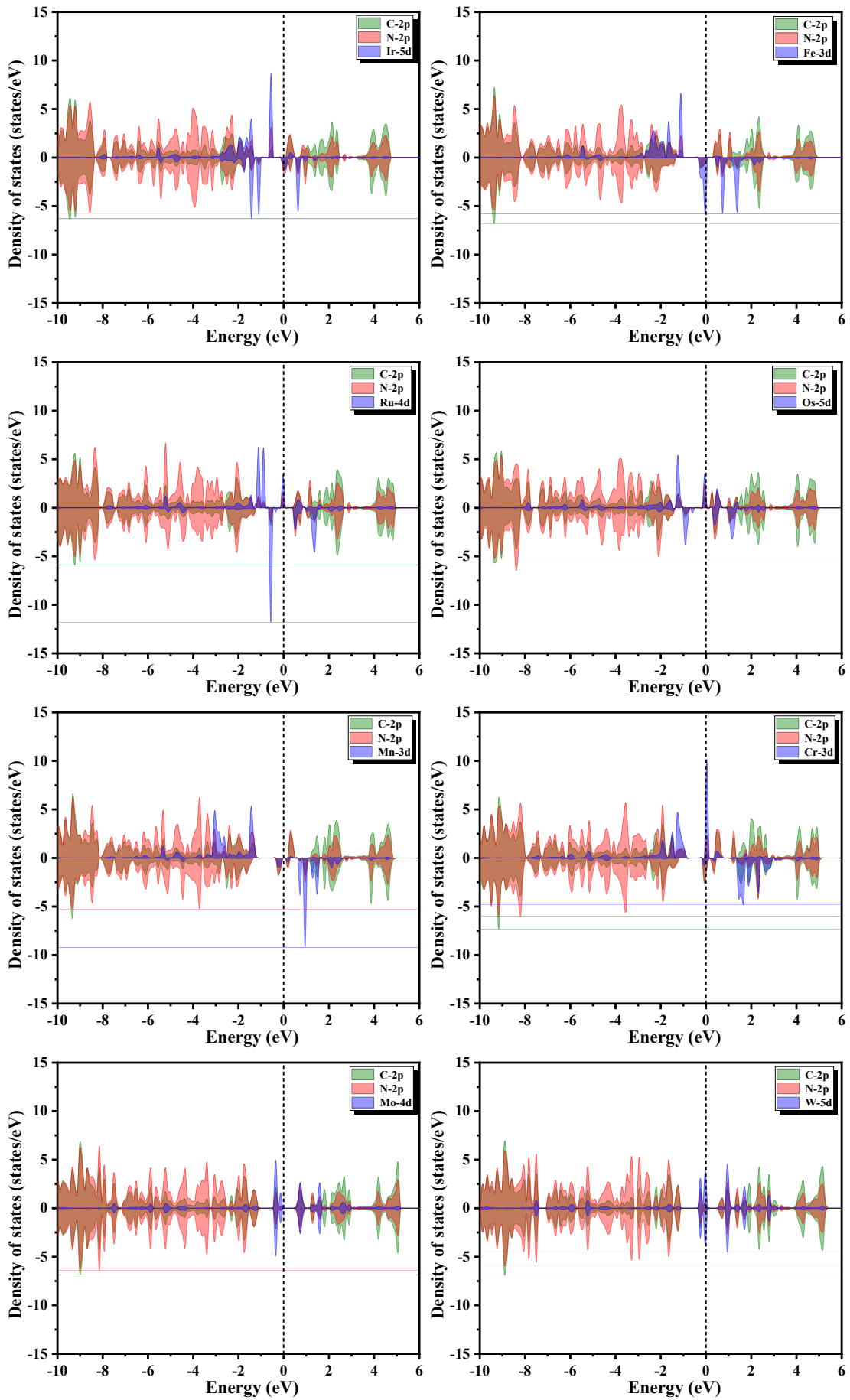


Fig. S2 Scaling relationship between the charge transfer quantity (Δq) and adsorption energy (E_{ad}) of TMs.





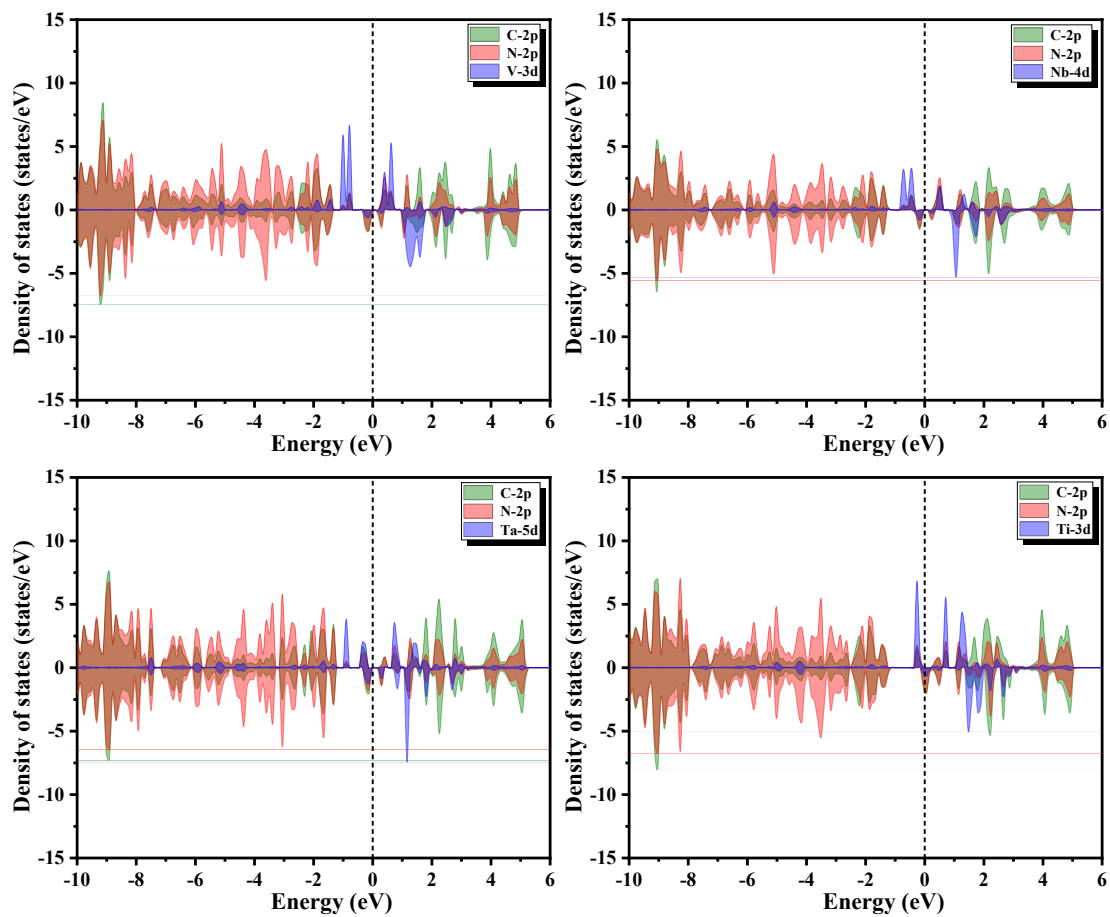


Fig. S3 Density of states of TM@C₇N₆.

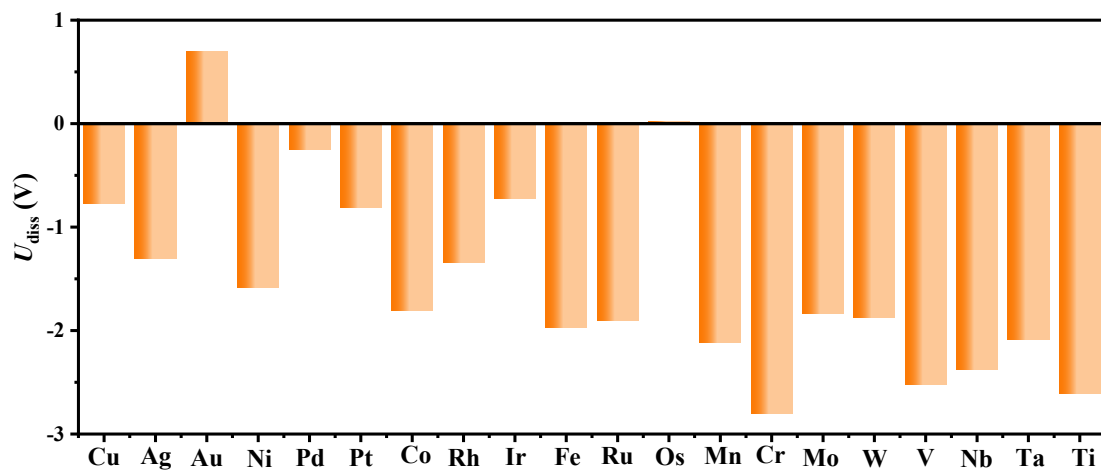


Fig. S4 Dissolution potential of TM@C₇N₆.

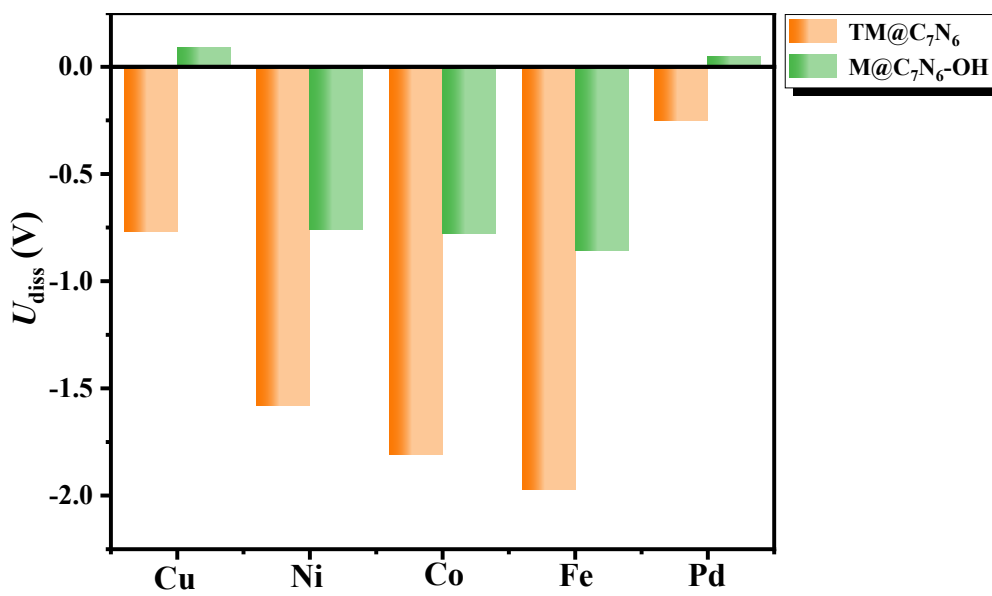
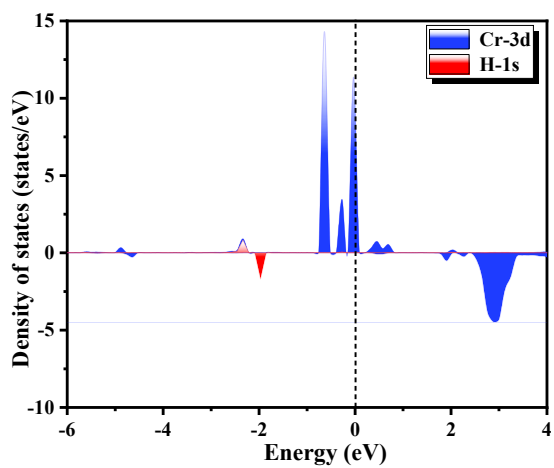
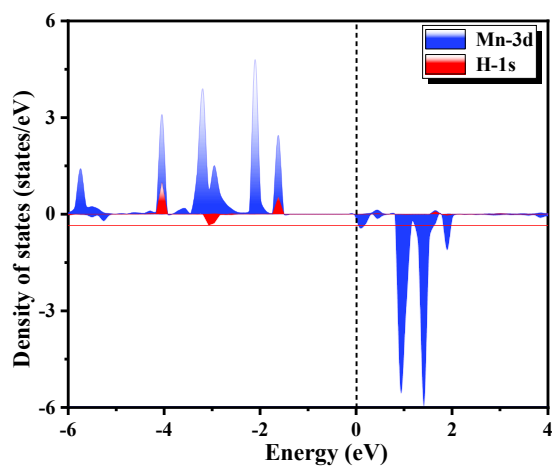
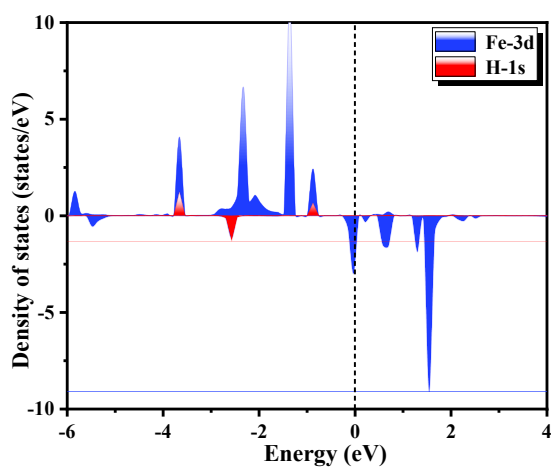
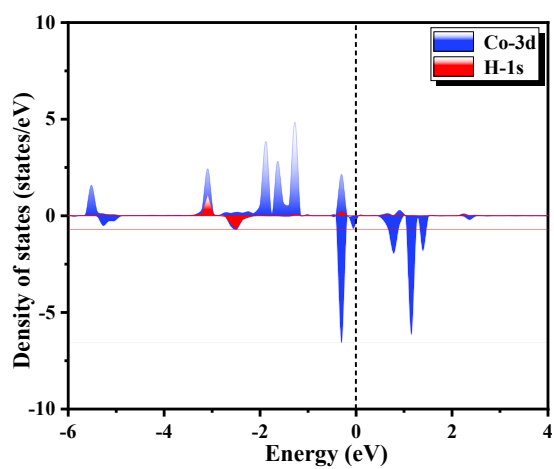
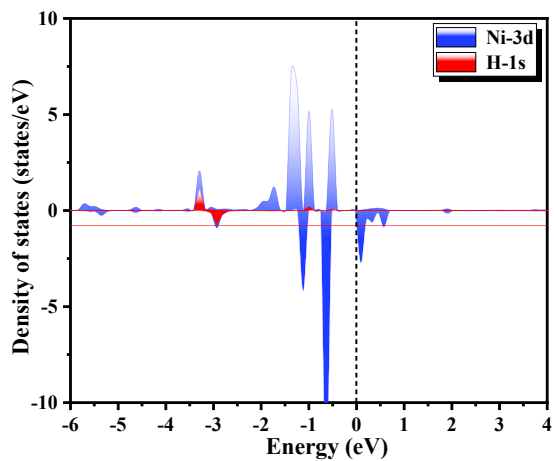
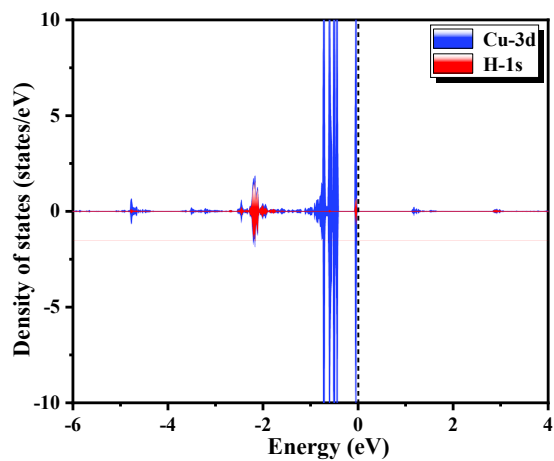


Fig. S5 Comparison of dissolution potential between TM@C₇N₆ between TM@C₇N₆-OH.



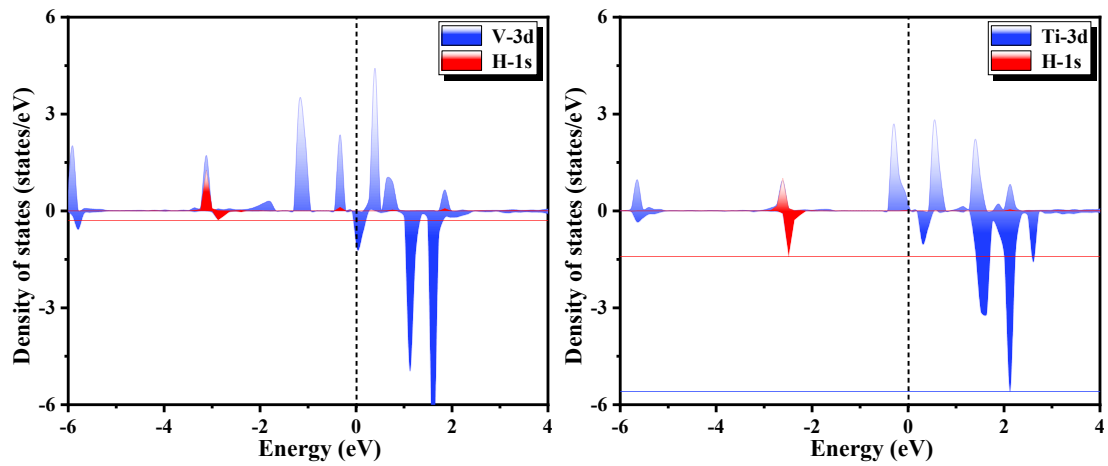
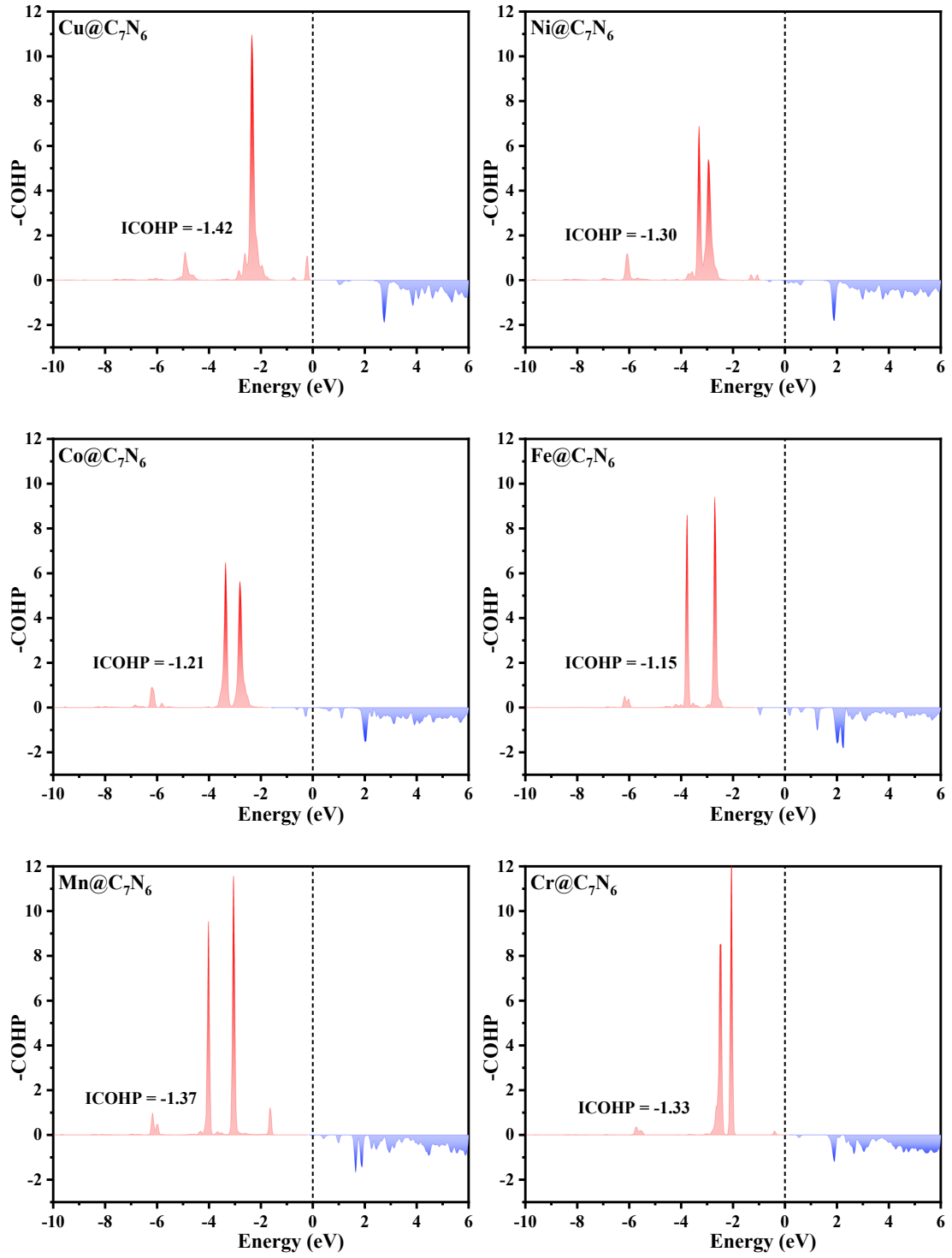


Fig. S6 Projected density of states of H adsorption on $\text{TM}@C_7N_6$.



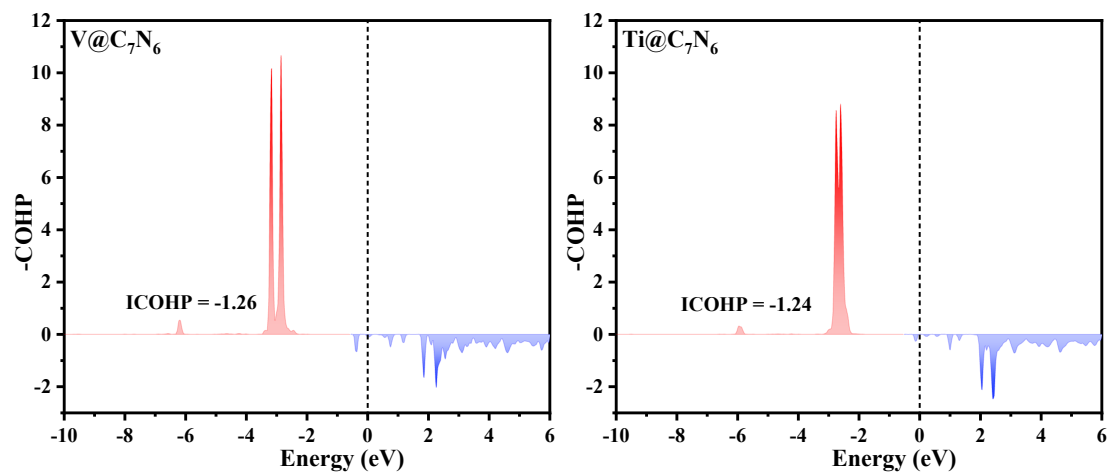
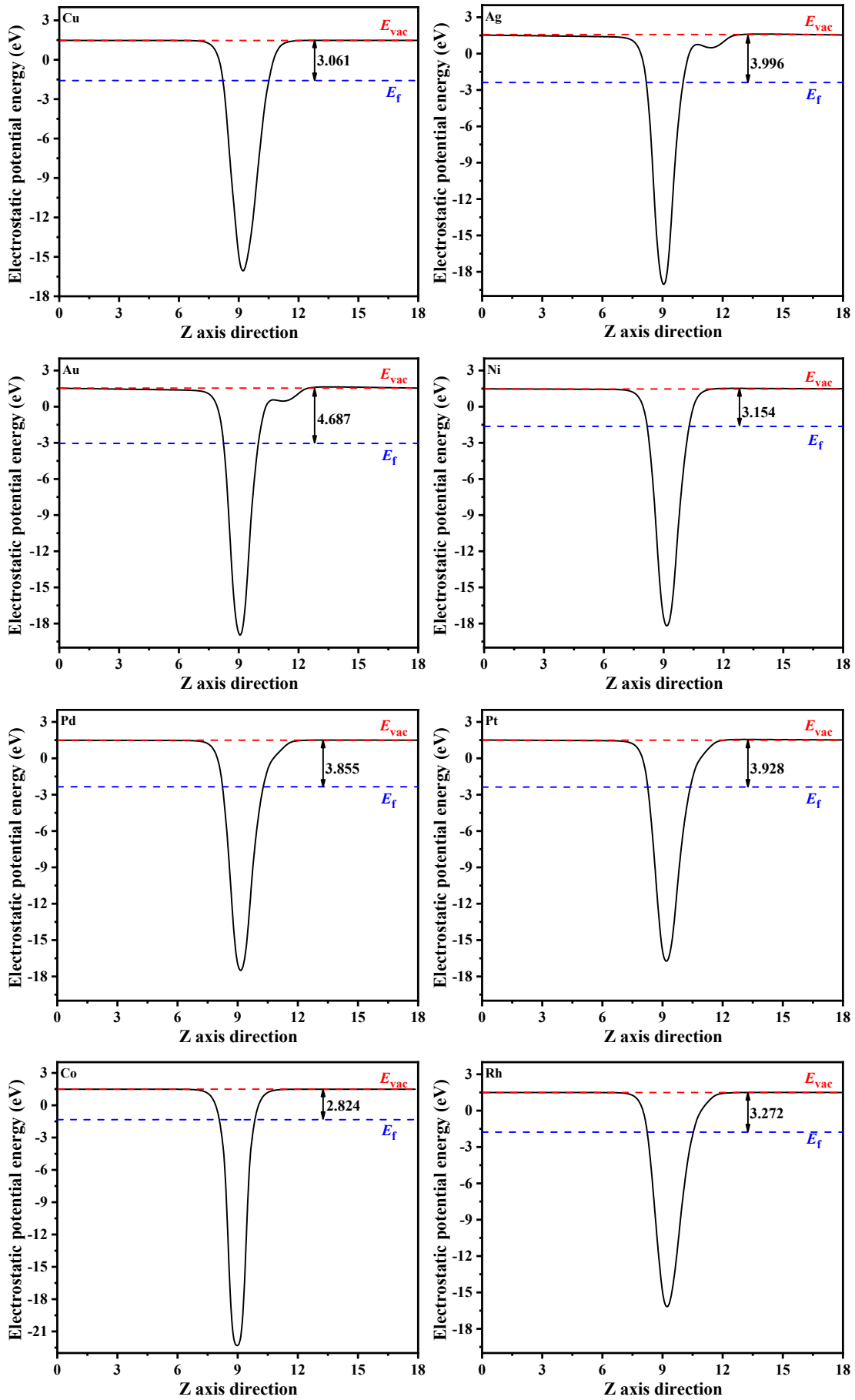
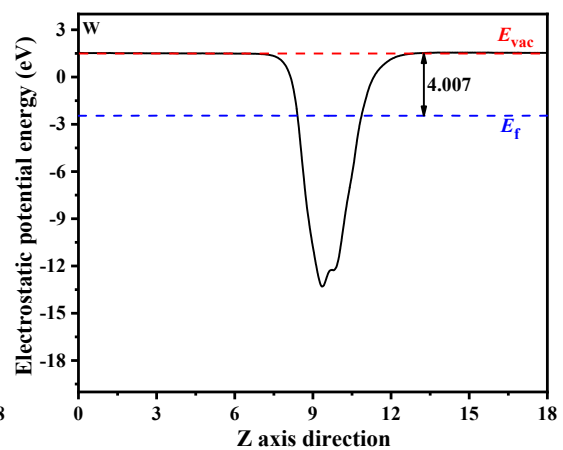
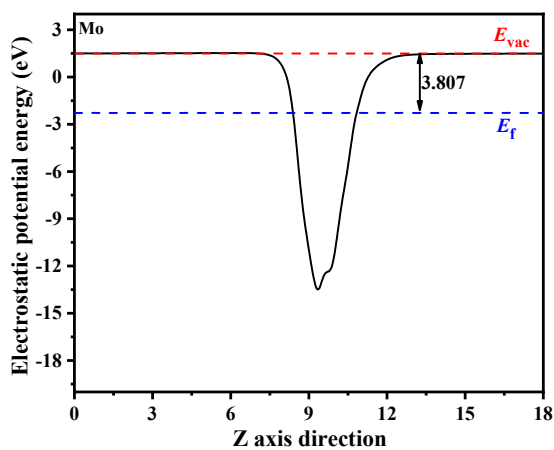
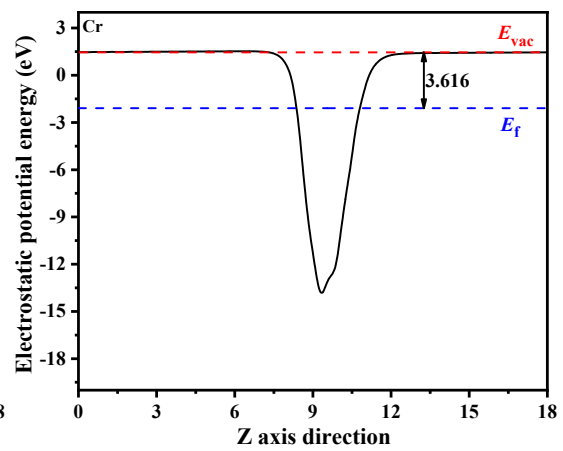
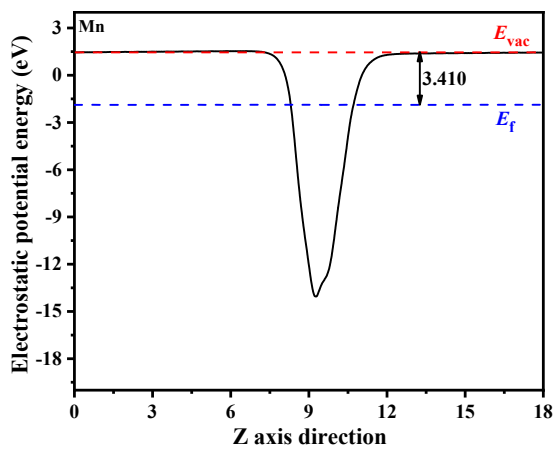
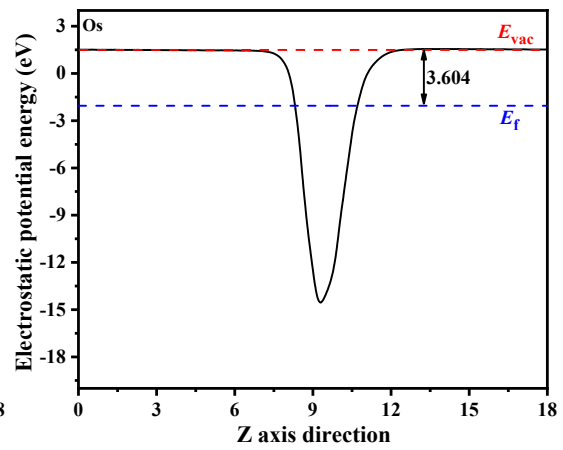
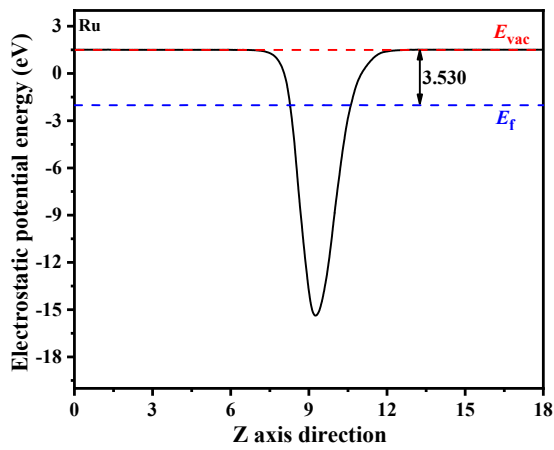
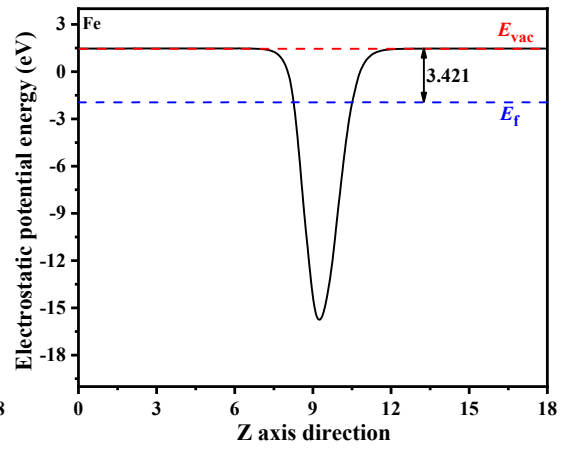
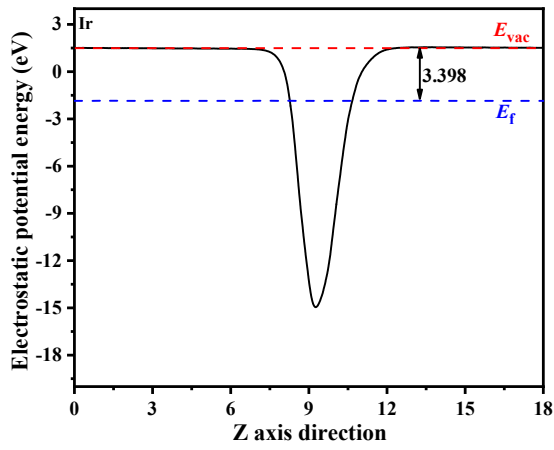


Fig. S7 Projected crystal orbital Hamiltonian population (pCOHP) of H adsorption on $TM@C_7N_6$.





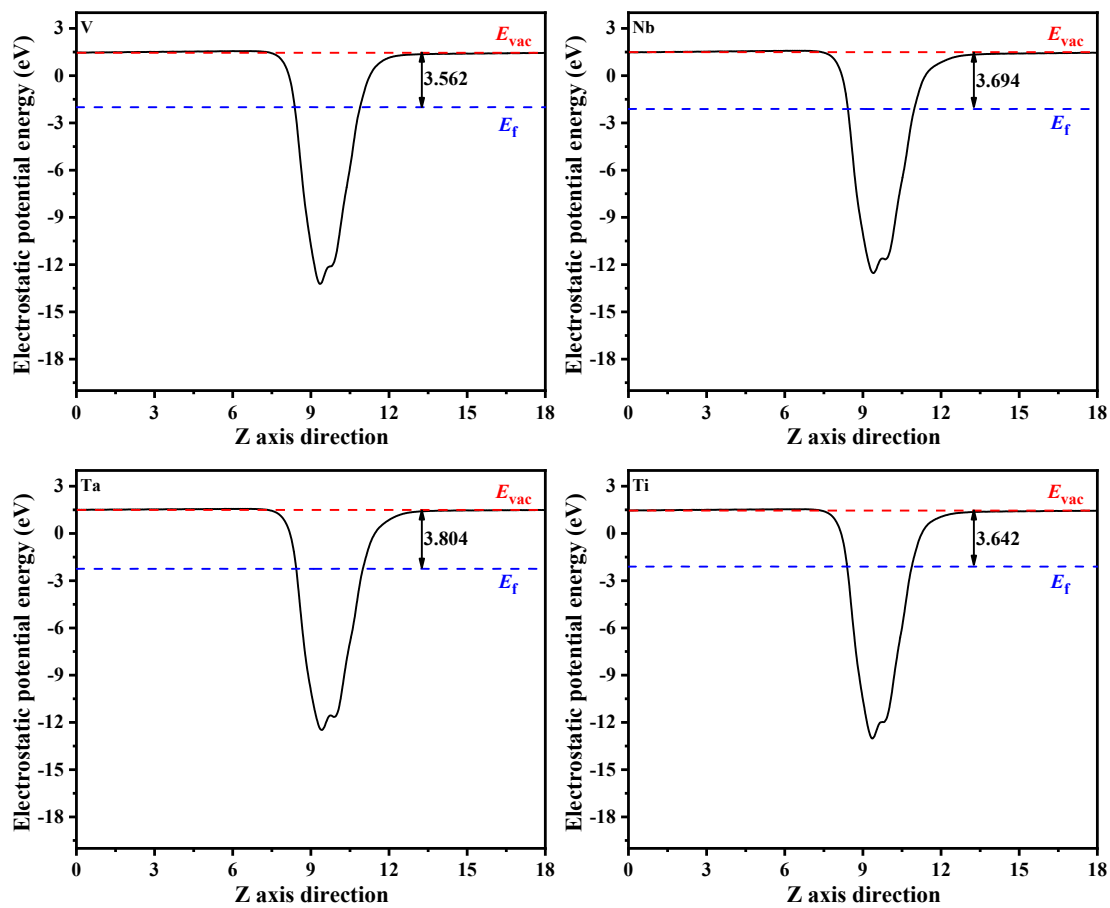


Fig. S8 Calculated work functions for TM@C₇N₆.

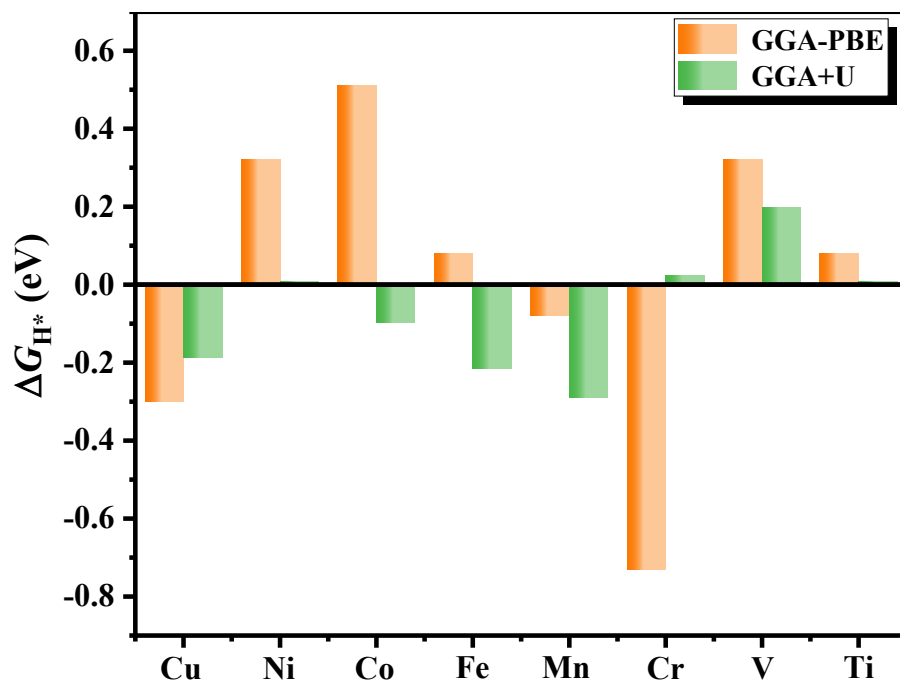


Fig. S9 Comparison of the calculated ΔG_{H^*} values for TM@C₇N₆ using the GGA-PBE and GGA+U methods.

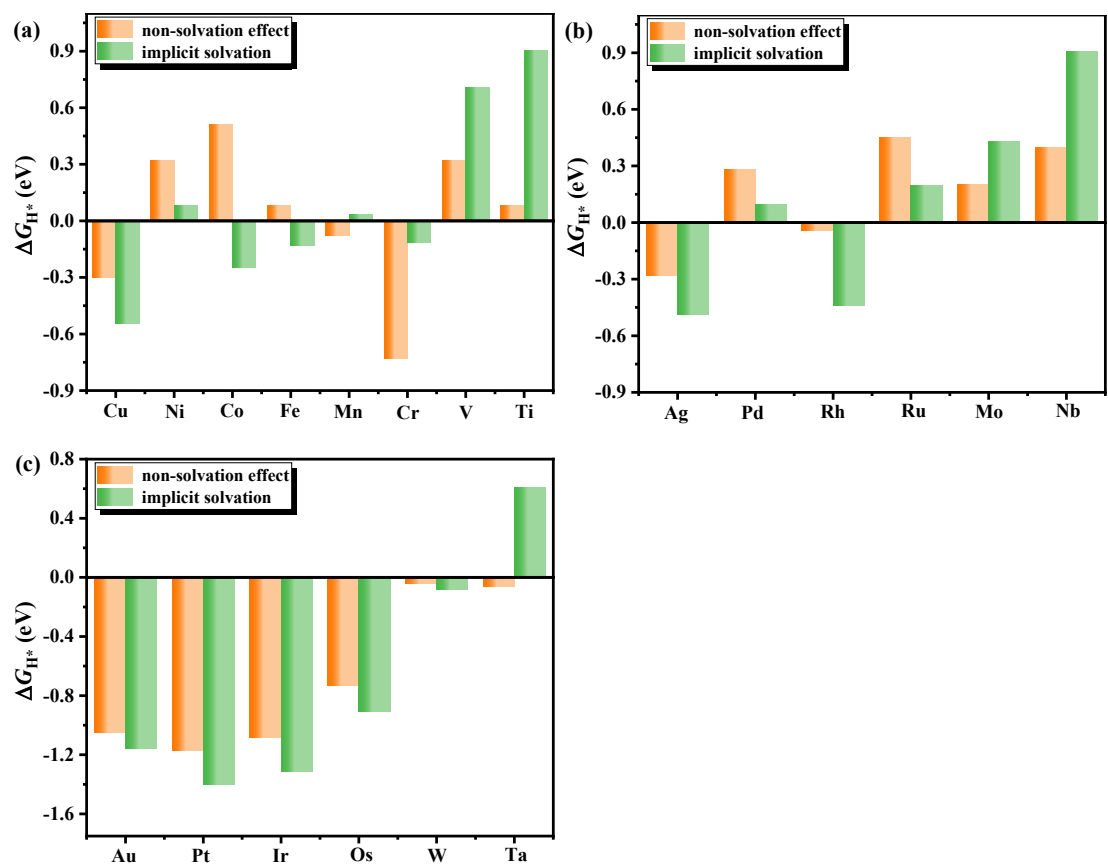


Fig. S10 Comparison of the calculated ΔG_{H^*} values for TM@C₇N₆ with and without solvation effects.